



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Yi Ding  
Assignee: Mosel Vitelic, Inc.  
Title: Nonvolatile Memory Cell With Multiple  
Floating Gates Formed After the Select Gate  
Application No.: 10/631,941 Filing Date: July 30, 2003  
Examiner: Unknown Group Art Unit: Unassigned  
Docket No.: M-15171 US

San Jose, California  
April 15, 2004

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR § 1.97(b)**

Dear Sir:

Pursuant to 37 CFR § 1.56, § 1.97 and § 1.98, the documents listed on the accompanying form PTO-1449 are called to the attention of the Examiner for the above patent application. Copies of these documents are enclosed except for United States Patents and United States Published Patent Applications.

Citation of these documents shall not be construed as:

1. an admission that the documents are necessarily prior art with respect to the instant invention;
2. a representation that a search has been made, other than as described above; or
3. an admission that the information cited herein is, or is considered to be material to patentability as defined in § 1.56(b).

No fee is believed to be required. If a fee is required for this Information Disclosure Statement, please charge the fee to Deposit Account No. 50-2257. This paper is being submitted in duplicate.

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on April 15, 2004.

*Michael Shenker* 4-15-04  
Attorney for Applicant Date of Signature

Respectfully submitted,

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U.S. Department of Commerce, Patent and Trademark Office				Atty Docket No.		Serial No.	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary)				M-15171 US		10/631,941	
				Applicant			
Yi Ding				Filing Date		Group	
				July 30, 2003		Unassigned	

  

U.S. Patent Documents							
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
	AA	6,420,231	16 Jul. 2002	Harari et al.			
	AB	2003/0218908 A1	27 Nov. 2003	Park et al.			
	AC	2004/0004863 A1	8 Jan. 2004	Wang			
	AD						
	AE						
	AF						
	AG						
	AH						

  

Foreign Patent Documents								
							Translation	
		Document	Date	Country	Class	Subclass	Yes	No
	AI	EP 0 938 098 A2	25 Aug. 1999	Europe				
	AJ							
	AK							
	AL							

  

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)		
AM	United States Patent Application No. 10/798,475, entitled "Fabrication of Conductive Lines Interconnecting Conductive Gates in Nonvolatile Memories and Non-Volatile Memory Structures," Filed on March 10, 2004; Attorney Docket No. M-15296 US.	
AN	United States Patent Application No. 10/797,972, entitled "Fabrication of Conductive Lines Interconnecting First Conductive Gates in Nonvolatile Memories Having Second Conductive Gates Provided By Conductive Gates Lines, Wherein The Adjacent Conductive Gate Lines For The Adjacent Columns Are Spaced From Each Other, And Non-Volatile Memory Structures," Filed on March 10, 2004; Attorney Docket No. M-15297 US.	
AO		
AP		

  

Examiner	Date Considered
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.